

### Pb Free Plating Product

### MURF3020PTA thru MURF3060PTA





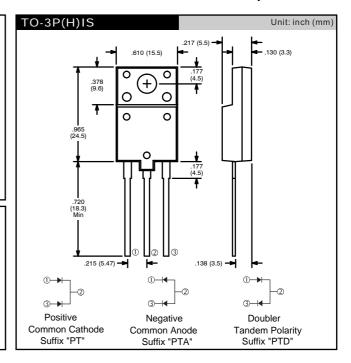
30.0 Ampere Insulated Common Anode Ultra Fast Recovery Rectifiers

# **Features**

- ♦ Dual rectifier construction, positive center-tap
- ♦ Plastic package has Underwriters Laboratory Flammability Classification 94V0
- ♦Glass passivated chip junctions
- ♦ Superfast recovery time, high voltage
- ♦Low forward voltage, high current capability
- ♦Low thermal resistance
- ♦Low power loss, high efficiency
- ♦ High temperature soldering guaranteed: 260°C, 0.16"(4.06mm)from case for 10 seconds

## **Mechanical Data**

- ♦Terminals: Pure tin plated, lead free solderable per MIL-STD-750. Method 2026
- ♦ Polarity: As marked
- Mounting position: Any
- ♦ Mounting torque: 10in-lbs. Max.
- ♦Weight: 0.2 ounce, 5.6 gram approximately



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

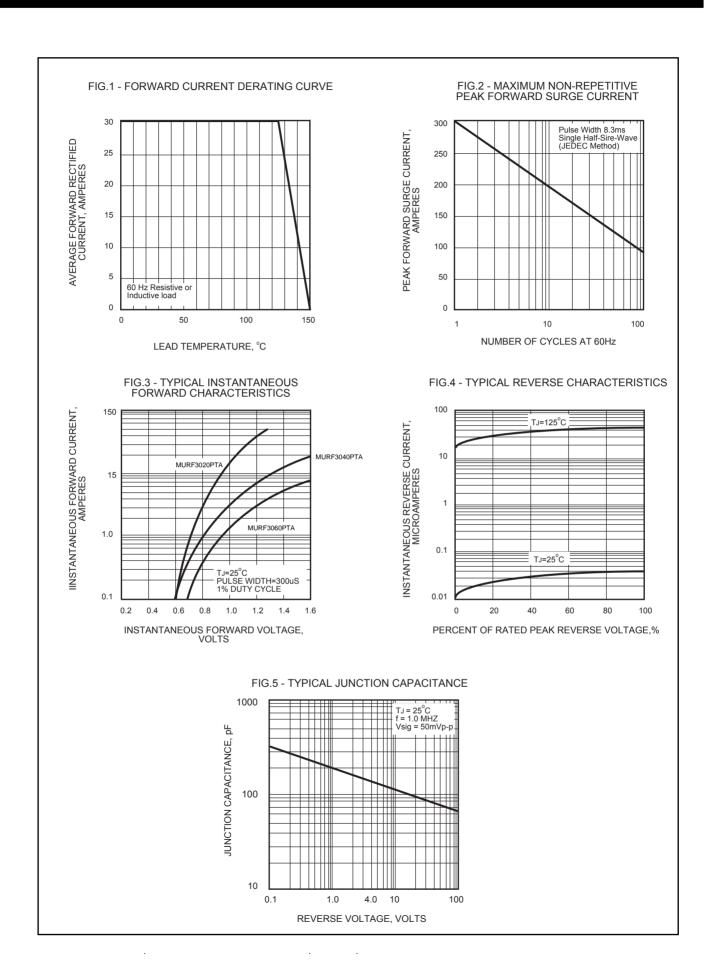
	SYMBOL	MURF3020PT MURF3020PTA MURF3020PTD	MURF3040PT MURF3040PTA MURF3040PTD		
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=125°C	IF(AV)	30.0			А
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	lfsm	300			А
Maximum Instantaneous Forward Voltage @ 15.0 A	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @Tj=25°C At Rated DC Blocking Voltage @Tj=125°C	lR	10 500			uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35			nS
Typical junction Capacitance (Note 2)	CJ	150			pF
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to +150			°C

NOTES: (1) Reverse recovery test conditions IF = 0.5A IR = 1.0A Irr = 0.25A.

- (2) Thermal Resistance junction to terminal.
- (3) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

Rev.04





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